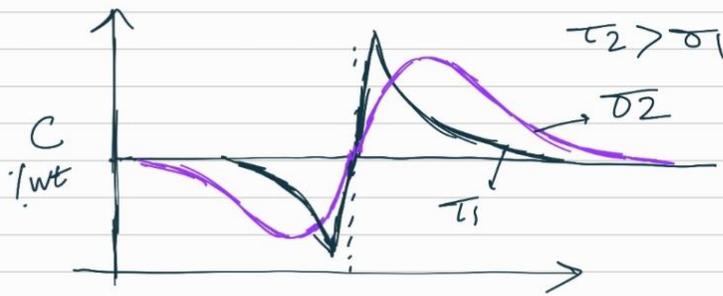
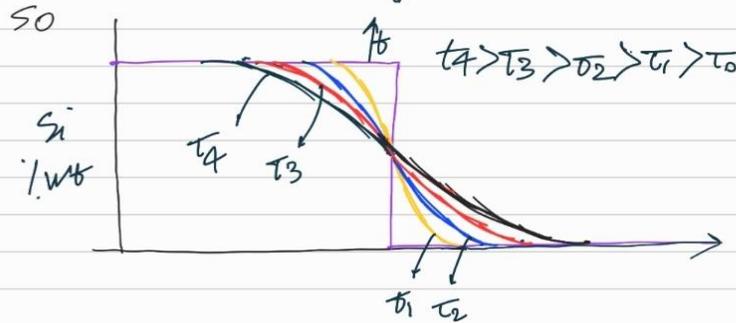


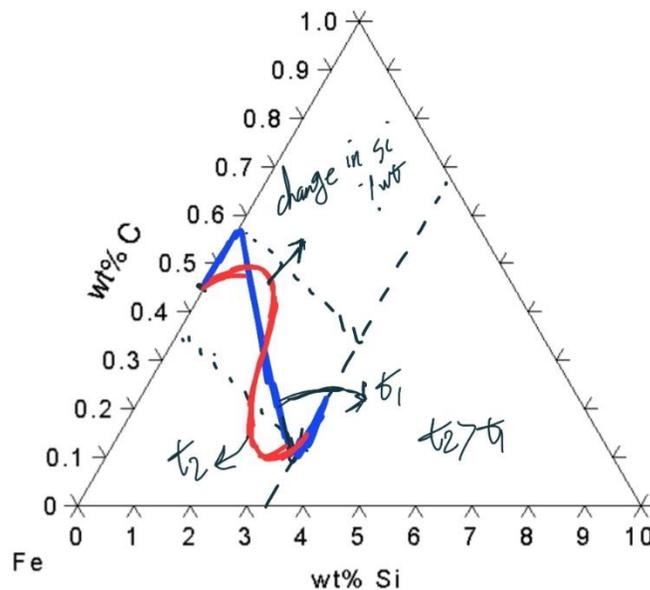
Q1.

Before starting it should be considered
 C has a diffusion coefficient of 1000 times
 faster than Si so Si needs longer time

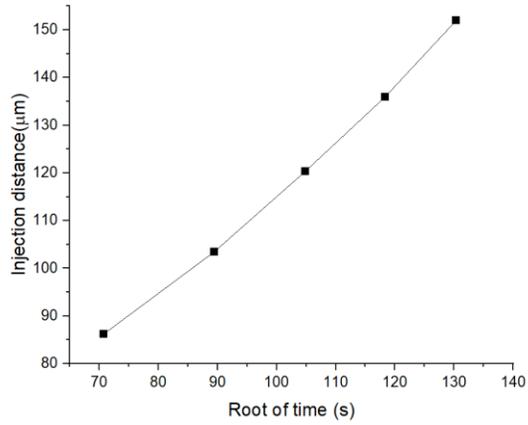
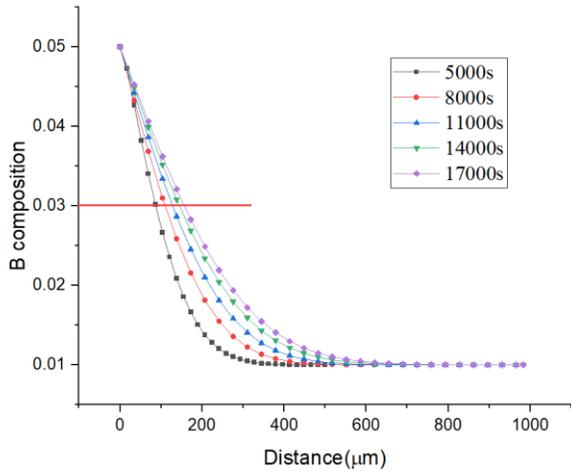
Mostafa
 Habibi
 2022/12/24



For diffusion path the Darken's uphill graph it
 should be considered at carbon rich side, high concentration
 of carbon causes C diffusion to opposite side. Also in Si rich
 side chemical potential is higher which causes Carbon diffusion

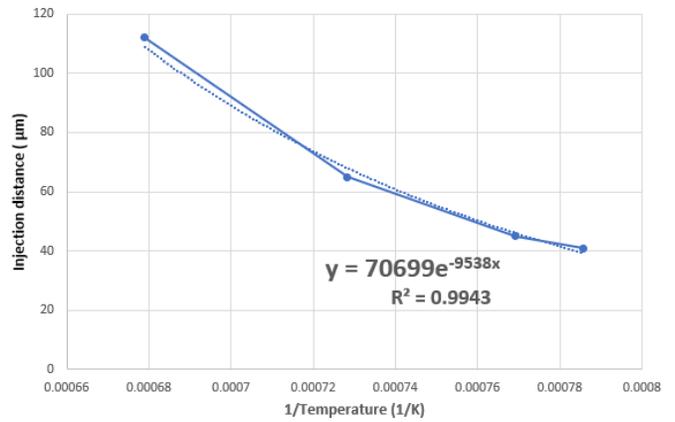
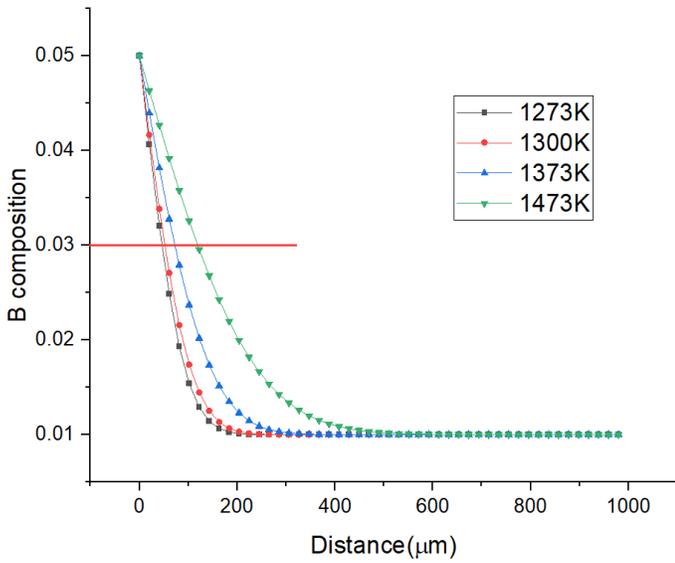


Q2 a)



injection distance $\propto \sqrt{t}$

b)



injection distance $\propto \exp(-\frac{1}{T})$

c)

we know $\alpha = \sqrt{D\delta}$

also $D = D_0 \exp(-\frac{Q}{RT})$ then

$$\alpha = \sqrt{D_0} e^{-\frac{Q}{2RT}}$$

↓ ln from both sides

$$\ln \alpha = \frac{1}{2} \ln D_0 - \frac{Q}{2R} \frac{1}{T}$$

now if we plot $\ln(\alpha) - -\frac{1}{T}$

$$Q = 99538 \times 8.3 \times 2 = 165330$$

Plot:

